## **Supplementary Information**

## How Spin State and Oxidation Number of Transition Metal Atoms Determine

## Molecular Adsorption: A First-Principles Case Study for NH<sub>3</sub>

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**Fig. S1.** The top views of optimized  $TM@S_v$ -SnS<sub>2</sub> structures, with Sc~Zn atoms correspond to (a)-(j), respectively.



**Fig. S2.** The total electronic density of states for the substrates of  $TM@S_v$ -SnS<sub>2</sub> without TM atoms in different electron number n, together with case of  $S_v$ -SnS<sub>2</sub> for comparison.



**Fig. S3.** The upper/lower part corresponds to the top/side views of  $NH_3$  adsorbed at  $TM@S_v$ -SnS<sub>2</sub> surfaces, with Sc~Zn correspond to (a)-(j). The N and H atoms are in silver white and pink, respectively.



**Fig. S4.** The size effect of supercell on the  $NH_3$  adsorption at  $TM@S_v$ -SnS<sub>2</sub> in different even electron number n. For clear, the highest values for both (4×4) and (5×5) cases are set to zero.



**Fig. S5.** The top and side views of charge density difference of  $NH_3@TM@S_v-SnS_2$  structures, with  $Sc \sim Zn$  correspond to (a)-(j), respectively. The purple and cyan areas indicate electron depletion and accumulation, with an isosurface of  $10^{-3} e/Å^3$ .



*Fig. S6.* The DOS of  $NH_3@TM@S_v$ -SnS<sub>2</sub> with TM atoms in even electron number n. Star \* denotes  $NH_3$  adsorbed at surface.



Fig. S7. The projected DOS of 3d orbital as well as  $3\sigma$  orbital of adsorbed NH<sub>3</sub> for TM atoms in even electron number n. The corresponding interacted orbitals are also provided in the inset, with an isosurface of  $10^{-7} e/Å^3$ , respectively.



**Fig. S8.** (Color online) (a) The illustration of outermost valence electron filling in the 3d orbitals of TM ions in TM@S<sub>v</sub>-Sn for  $V^{2+}$ ,  $Cr^{2+}$ ,  $Co^0$ , and  $Ni^0$  ions. The corresponding frontier orbitals between  $3\sigma$  of  $NH_3$  and 3d orbital of TM ions with (b) dxz orbital, and (c) dz<sup>2</sup> orbital, respectively.